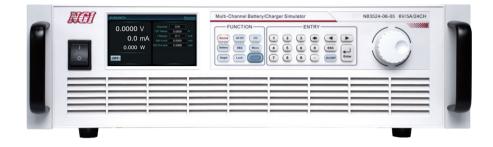


N83524 Series Multi-channel Dual-quadrant Battery Simulator



Product Introduction

N83524 is a programmable battery simulator with low-power, multi-channel and high-accuracy. By adopting dual-quadrant design, the current can be charged and discharged, which can satisfy the needs of BMS test and consumer electronics ATE test. Its voltage accuracy is up to 0.6mV, supporting µA-level current measurement, standalone up to 24 channels. The channels are isolated from each other, which is convenient for series connection. N83524 supports both local operation and remote operation via LAN/RS232/CAN interface. N83524 application software is easy to use, which can meet demands of battery simulators in multi-channel, multi-parameter, and complex test environments.

Application Fields

- BMS/CMS test for new energy vehicle, UAV and energy storage
- Battery protection board test
- Portable consumer electronics R&D and production, such as mobiles, bluetooth earphones, smartwatch, etc.
- Electric tools manufacturing test, such as electric screw driver
- Power supply to low power products, such as DC-DC, wireless charging products
- Battery maintenance device test

Main Features

- Voltage range: 0-6V
- Voltage accuracy up to 0.6mV
- High integration, standalone up to 24 channels, each channel isolated
- µs-level dynamic response, simulating the characteristics of real battery
- Doptional NB108 series products to achieve fault simulation and nA-level current measurement
- Supporting charge mode, battery simulation, SEQ test, SOC test
- 4.3 inch high-definition color LCD screen, local/remote control, standard application software
- LAN port,RS232 interface,CAN interface; dual LAN ports, convenient for cascade application

Active/passive balancing test

By bidirectional current design, each channel supports up to 5A current input and output. Users can customize the battery charge and discharge model, which fully meets the requirements of BMS active/passive balancing test.

Current range: ±1A/±3A/±5A
µA-level current measurement

▶ Voltage ripple noise ≤2mVrms



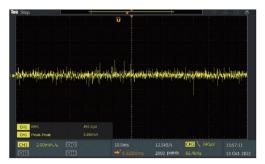
Active Balancing Diagram



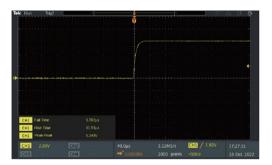




N83524 series has fast dynamic response capability. The response time of load varying from 10% to 90% and voltage recovering within 50mV of previous voltage is less than 100µs, which can ensure the rise and fall waveform of voltage is high-speed and without overshoot, and provide stable output voltage to the DUT.



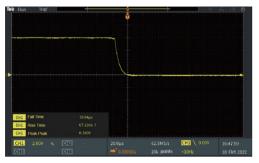
▲ Voltage Ripple Noise <2mVrms



▲ Voltage Rise Time at Full Load <40µs

 Text
 Stop
 Image: Stop
 Image:

▲ Transient Recovery Time < 100µs

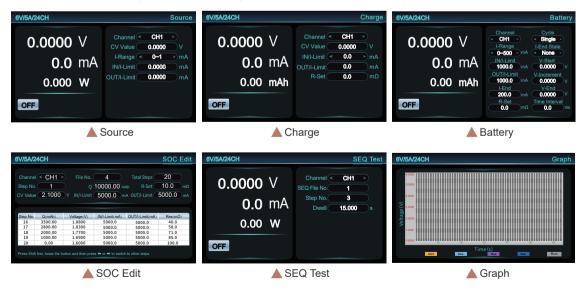


▲ Voltage Fall Time at No Load <100µs

Battery simulation suitable for BMS chips test of various specifications

N83524 series battery simulators have multiple functions and features, supporting Source, Charge, Battery Simulation, SOC Test, SEQ Test, Graph, etc.N83524 can achieve high-precision voltage and current measurements to quickly verify the response of various portable electronic products under different battery conditions.

One device can achieve multiple uses, streamline test equipment and optimize test procedures. N83524's internal circuit is optimized for different chips, which can be adapted to test BMS chips of various specifications.



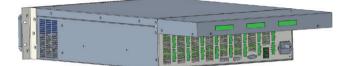


2

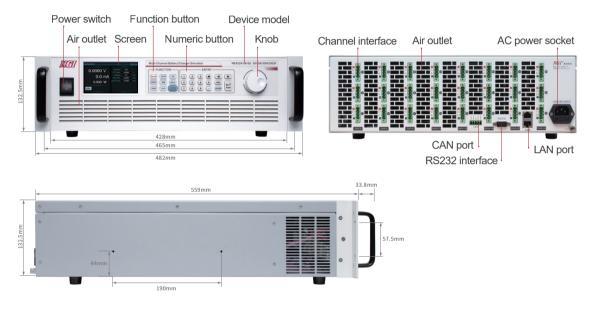


Optional fault simulation unit

N83524 integrates 24 independent output channels in a 19-inch 3U chassis. By optional NB108-2 fault simulation unit (as shown in the below figure), it can realize simulation of 24-channel built-in positive&negative short circuit, positive&negative open circuit and reverse polarity. By NB108-2, it can improve the integration of test system, reduce complicated wiring, save space and reduce costs for users.



Product Dimension





Technical Data Sheet

Model	N83524-06-01		N83524-06-03		N83524-06-05		
Current	±1A/CH		±3A/CH		±5A/CH		
Voltage			6V/CH				
Power	6W/CH		18W/CH		30W/CH		
Channels			24CH				
		С	V Mode				
Range	0~6V						
Setting Resolution	0.1mV						
Setting Accuracy (23±5°C)	0.6mV						
Readback Resolution	0.1mV						
Readback Accuracy (23±5°C)	0.6mV						
Temperature Coefficient	20ppm/℃						
Long-term Stability	80ppm/1000h						
Voltage Ripple Noise	≤2mVrms						
CC Mode							
Range	-1~1A	-1~1mA	-3~3A	-1~1mA	-5~5A	-1~1mA	
Setting Resolution	0.1mA	0.1µA	0.1mA	0.1µA	0.1mA	0.1µA	
Setting Accuracy (23±5℃)	1mA	1µA	3mA	1µA	5mA	1µA	
Readback Resolution	0.1mA	0.1µA	0.1mA	0.1µA	0.1mA	0.1µA	
Readback Accuracy (23±5℃)	1mA	1µA	3mA	1µA	5mA	1µA	
Temperature Coefficient (0~40℃)	30ppm/℃						
Long-term Stability	100ppm/1000h						
	Dynamic Characteristics						
Voltage Rise Time	<40µs (no load) (10%-90%F.S. Variation Time)						
Voltage Rise Time	<40µs (pure resistive full load) (10%-90%F.S. Variation Time)						
Voltage Fall Time	<100µs (no load) (90%-10%F.S. Variation Time)						
Voltage Fall Time	<100µs (pure resistive full load)(90%-10%F.S. Variation Time)						
Transient Voltage Drop ¹	350mV						
Transient Recovery Time ²	<100µs						
	Others						
Load Regulation	0.01%+0.2mV						
Isolation (Output to ground)	1500VDC						
Isolation (Inter-channel)	500VDC						
Communication Response Time	≤10ms						
Interface	LAN/RS232/CAN						
AC Input	Single phase, 100~240V AC, current≤8A@220V,≤14A@110V, frequency 47Hz~63Hz						
Temperature	Operating temperature: 0° ~40°C, storage temperature: -20°C ~60°C						
Operating Environment	Altitude <2000m, relative humidity: 5%~90%RH(non-condensing), atmospheric pressure: 80~110kPa						
Net Weight	Approx. 20kg						
Dimension	3U, 132.5(H)*482.0(W)with handle*559.0(D)mm 3U, 132.5(H)*482.0(W)with handle*718.0(D)mm with NB108-2						

Note 1: Load varies from10% to 90% by full voltage output.

Note 2: Load varies from 10% to 90% by full voltage output, with voltage recovering within 50mV of previous voltage.

Note 3: For other specifications, please contact NGI.

Note 4: All specifications are subject to change without notice.



4